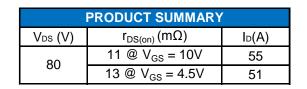
N-Channel 80-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

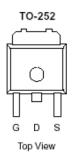
Typical Applications:

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits



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ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V_{DS}	80	V	
Gate-Source Voltage		V _{GS}	±20	v	
Continuous Drain Current ^a	T _A =25°C	I _D	55	А	
Pulsed Drain Current ^b		I _{DM}	200	A	
Continuous Source Current (Diode Conduction) ^a		ا _s	55	А	
Power Dissipation ^a	T _A =25°C	PD	50	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C	

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	$R_{ extsf{ heta}JA}$	40	°C/W	
Maximum Junction-to-Case	$R_{ extsf{ heta}JC}$	3	C/ VV	

Notes

a. Package Limited

b. Pulse width limited by maximum junction temperature

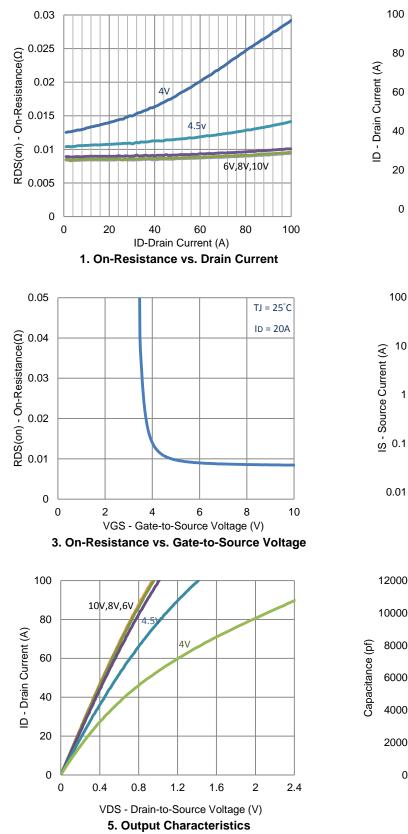
Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 64 \text{ V}, V_{GS} = 0 \text{ V}$		1		uA	
	I _{DSS}	V _{DS} = 64 V, V _{GS} = 0 V, T _J = 55°C			25	uA	
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	27.5			А	
Drain Source On Resistance	r	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 27.5 \text{ A}$			11	mΩ	
Drain-Source On-Resistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 25.3 \text{ A}$			13		
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 27.5 \text{ A}$		35		S	
Diode Forward Voltage	V_{SD}	$I_{S} = 27 \text{ A}, V_{GS} = 0 \text{ V}$		0.82		V	
Dynamic							
Total Gate Charge	Qg			58		nC	
Gate-Source Charge	Q_gs	$V_{DS} = 40 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		14			
Gate-Drain Charge	Q_{gd}			39			
Turn-On Delay Time	t _{d(on)}			19			
Rise Time	t _r	$V_{DS} = 40 \text{ V}, \text{ R}_{L} = 2 \Omega, \text{ I}_{D} = 20 \text{ A},$		45		ns	
Turn-Off Delay Time	t _{d(off)}	V_{GEN} = 10 V, R_{GEN} = 6 Ω		178			
Fall Time	t _f			62			
Input Capacitance	C _{iss}			5052			
Output Capacitance	C _{oss}	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz		471		pF	
Reverse Transfer Capacitance	C _{rss}			446			

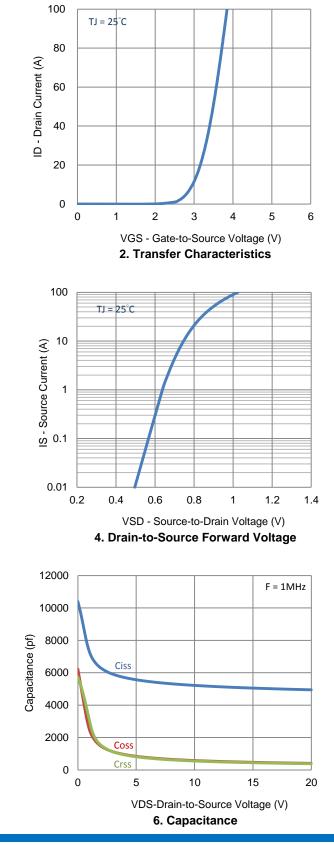
Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

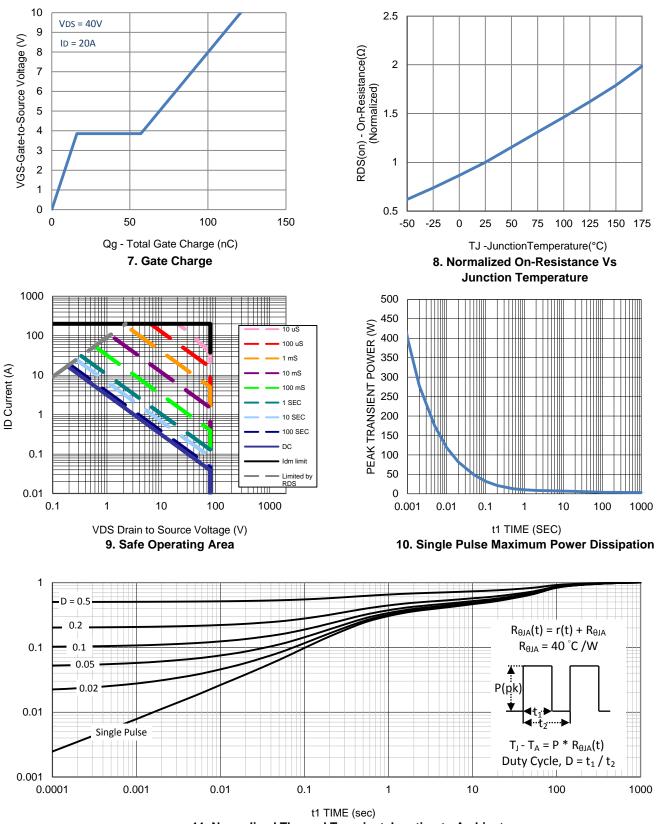
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Typical Electrical Characteristics



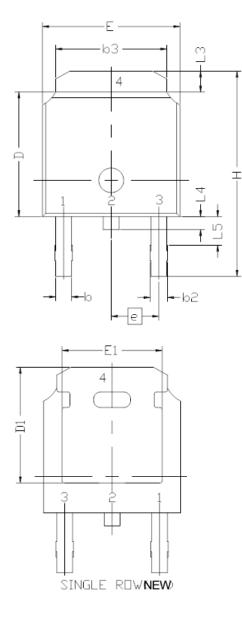
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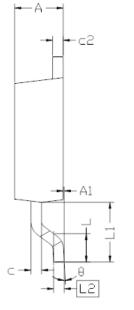


Typical Electrical Characteristics

11. Normalized Thermal Transient Junction to Ambient

Package Information





	DIMENS		REQMTS
SYMBOL	MIN	NDM	MAX
E	6.40	6.60	6.731
L	1.40	1.52	1.77
L1	2	.743 R	ÈF
L2		.508 BS	C D
L3	0.89		1.27
L4	0.64		1.01
L5			
D	6.00	6.10	6.223
Н	9.40	10.00	10.40
b	0.64	0.76	0.88
b2	0.77	0.84	1.14
b3	5.21	5.34	5.46
e		286 BS	
A	2.20	2.30	2.38
A1	0		0.127
C	0.45	0.50	0.60
c2	0.45	0.50	0,58
D1	5.30		
E1	4.40		
θ	0°		10°

Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.